2SC5725

Silicon NPN epitaxial planar type

For DC-DC converter

■ Features

- ullet Low collector-emitter saturation voltage $V_{CE(sat)}$
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	20	V	
Collector-emitter voltage (Base open)	V _{CEO}	15	V	
Emitter-base voltage (Collector open)	V _{EBO}	5	V	
Collector current	I_C	2	A	
Peak collector current	I_{CP}	6	A	
Collector power dissipation *	P _C	600	mW	
Junction temperature	Tj	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	

Note) *: Measure on the ceramic substrate at $15 \text{ mm} \times 15 \text{ mm} \times 0.6 \text{ mm}$

Unit: mm 0.40^{+0.10}_{-0.05} 0.16^{+0.10}_{-0.06} 0.16^{+0.10}_{-0.06} 10 11 12 12 13 10 10 11: Base 2: Emitter 3: Collector EIAJ: SC-59 Mini3-GI Package

Marking Symbol: 3C

■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \mu{\rm A}, I_{\rm E} = 0$	20			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	15			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 10 \mu\text{A}, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$			0.1	μΑ
Forward current transfer ratio *	h _{FE1}	$V_{CE} = 2 \text{ V}, I_{C} = 100 \text{ mA}$	200		800	_
	h _{FE2}	$V_{CE} = 2 \text{ V}, I_{C} = 1.5 \text{ A}$	120			
Collector-emitter saturation voltage *	V _{CE(sat)}	$I_C = 0.5 \text{ A}, I_B = 25 \text{ mA}$		40	100	mV
	le.	$I_C = 1.5 \text{ A}, I_B = 30 \text{ mA}$		130	280	
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		280		MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		15	25	pF
(Common base, input open circuited)						

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

^{2. *:} Pulse measurement

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